Supporting information:

High-performance silicon photoanode enhanced by gold nanoparticles for efficient water oxidation

Wenting $Hong^{\dagger \ddagger}$, $Qian\ Cai^{\dagger}$, $Rongcheng\ Ban^{\perp}$, $Xu\ He^{\dagger}$, $Chuanyong\ Jian^{\dagger}$, $Jing\ Li^{\dagger}$, $Jing\ Li^{\perp}$, $Wei\ Liu^{*\dagger}$

[†]CAS Key Laboratory of Design and Assembly of Functional Nanostructures, and Fujian Provincial Key Laboratory of Nanomaterials, Fujian Institute of Research on the Structure of Matter, Chinese Academy of Sciences, Fuzhou, Fujian, 350002, China

[‡]University of Chinese Academy of Sciences, Beijing, 100049, China

¹Department of Physics/Pen-Tung Sah Institute of Micro-Nano Science and Technology, Xiamen University, Xiamen, Fujian 361005, China

E-mail: liuw@fjirsm.ac.cn

S1. The height of the surface of NiAu/TiO $_2$ /n-Si photoanode with NiAu (2 nm/2 nm) catalyst

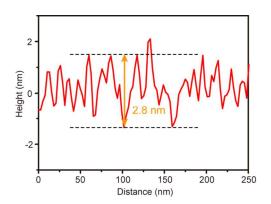


Figure S1. The corresponding height profile of the white line in Atomic force microscopy (AFM) image (figure 1c).

S2. The possible deposited process of NiAu catalyst

The structures of as-prepared samples are determined by X-ray photoelectron spectroscopy (XPS) using Ar K α radiation (ESCALAB 250Xi). The depth profile of Au 4f and Ni 2p signals are collected at various etch times using Ar ion milling method.

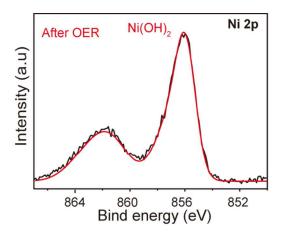


Figure S2. X-ray photoelectron spectroscopy (XPS) spectra of Ni 2p spectra for NiAu/TiO₂/n-Si photoanode after OER operation.

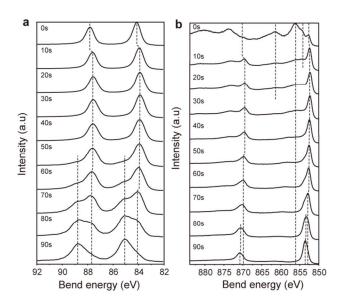


Figure S3. The depth profiling of a, Au, b, Ni for NiAu catalyst under different etching times.

S3. Photoelectrochemical characterization methods

In this study, all electrochemical reactions were measured using Ag/AgCl reference electrode at room temperature. However, all the measurements discussed are performed in 1M KOH solution electrolyte of pH = 14 using Pt counter electrode and converted to the reversible hydrogen electrode (RHE) unless specified. The converting equation is $E_{RHE} = E_{SCE} + 0.197 \text{ V} + 0.059*pH$, where E_{RHE} is the potential referred to RHE and E_{SCE} is the measured potential against saturated calomel electrode (SCE) electrode filled with 3.5 M KCl as the reference electrode. All the current density values given in the text refer to the visible area of the working electrode (1.0 cm²). The onset potential, defined as the potential to drive the current density of 1 mA/cm² for water oxidation, and the photocurrent density at 1.23 V versus RHE are the criterions in this work to evaluate the OER activity. They can be obtained from LSV curves. All data are collected without iR compensation. The OER testing is operated under visible light irradiation, and a UV-cutoff filter was employed to achieve visible-light (>420 nm) irradiation.

The photovoltage was defined as the difference between the potential to drive 1 mA/cm 2 through the illuminated n-Si photoanode and the dark p $^+$ -Si anode. The NiAu/TiO $_2$ /n-Si photoanode has a high photovoltage around 518 mV as shown in Figure S4 a.

Electrochemical impedance spectroscopy was performed in 1M KOM solution in dark, the AC voltage was 5 mV amplitude with the frequency range from 0.1 Hz to 10000 Hz. The initial potential is around their corresponding onset potential.

Table S1 OER catalytic parameters of recently-reported Ni-based and Si-based photoanodes.

Photoanodes	η_{θ}	J_{sc}	Electrolyte	Reference
	(V)	(mA/cm ²)		
NiAu (2nm/2 nm)/TiO ₂ /n-Si	-0.20	18.80	1М КОН	This work
Ni (2 nm)/TiO ₂ /n-Si	-0.13	8.62	1М КОН	This work
Ni ₈₀ Fe ₂₀ /TiO ₂ /n-Si	-0.17	21.5	1M KOH	ACS Catal. 2017, 7, 3277-3283.
np+-Si NiO _x	-0.18	29	1M KOH	J. Phys. Chem. Lett. 2015, 6, 592-598. S1
np + -Si/SiO _x /NiFe	-0.34	30.7	1M KOH	Adv. Energy Mater. 2016, 7, 1601805. S2
2 nm Ni/2 nm Ti/n-Si	-0.20	10.7	1 M KOH	J. Mater. Chem. A 2017, 5, 1996-2003. S3
5 nm Ni/SiO _X /n-Si	-0.078	0.8	1 M KOH	J. Mater. Chem. A 2016, 4, 8053-8060. ²⁸
Ni NP/SiO _X /n-Si	-0.16	3.5	1 M NaOH	ACS Energ. Lett. 2017, 2, 569-573. ²⁹
n-Si/TiO ₂ /Ni	-0.03	1.8	1 M KOH	ACS Appl. Mater. Interfaces 2015, 7,
				15189-15199. ³⁰
NiMoO ₄ /TiO ₂ /Si nanowire	0.85	0.014	1 M KOH	Nano Energ. 2017, 34, 8-14. S4
n-Si/SiO _{x,RCA} /CoO _x	-0.212	23.2	1 M KOH	Energy Environ. Sci. 2016, 9, 892-897.31
n-Si/NiO _x	0.13	0.2	0.25M Na ₂ SO ₄	Energy Environ. Sci. 2012, 5, 7872-7877. 14
CoO _x / SiO _x / np ⁺ Si	-0.13	17	1 M NaOH	J. Am. Chem. Soc. 2014, 136, 6191-6194. S5
Ni/SiO _x / n-Si	-0.16	10.47	1 M KOH	Science 2013, 342, 836-840. ¹⁶
Ni/TiO ₂ / np ⁺ -Si	-0.16	11	1 M KOH	Science 2014, 344, 1005-1009. ¹⁷
IrO _x /Ir/p ⁺ -n-Si	-0.18	13.8	1 M H ₂ SO ₄	J. Phys. Chem. Lett. 2014, 5, 3456-3461. S6
n-Si SiO _x TiO ₂ Ir	-0.21	8.34	1 M NaOH	Nat. Mater. 2015, 15, 99-105.8
Fe ₂ O ₃ /n-SiNW	-0.23	17.3	1M NaOH	Angew. Chem. Int. Ed. 2012, 51, 423-427. S7
n-Si/SiO _x /CoO _x /NiO _x	-0.24	27.7	1 M KOH	Energy Environ. Sci. 2015, 8, 2644-2649. S8
NiRuO _x / n-bSi	-0.25	1.34	0.25M Na ₂ SO ₄	Nano Lett. 2013, 13, 2064-2072. S9
Ir/TiO ₂ /SiO ₂ /p ⁺ n-Si	-0.3	4.8	PBS	Nat. Mater. 2011, 10, 539-544. 12
Ni(OH) ₂ -Au	0.12	/	1 M KOH	J. Am. Chem. Soc. 2016, 135, 16977-
				16987. ³⁵
AuNP/Hematite/SiNW	-1.25	2.6	1M NaOH	Nano Lett. 2014, 14, 18-23. 19

 η_0 : water oxidation overpotential at 1 mA/cm² current density; J_{sc} : the photocurrent density at

1.23 V versus RHE.

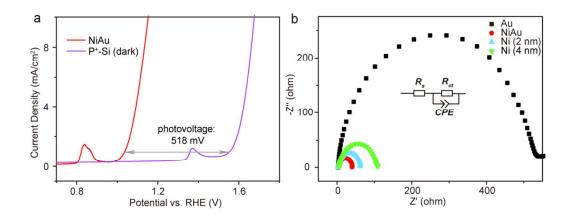


Figure S4 a, LSV curves for NiAu/TiO₂/n-Si and NiAu/TiO₂/p⁺-Si photoanodes. b, Nyquist diagrams for various metal/TiO₂/n-Si photoanodes, the inset shows the equivalent circuit model.

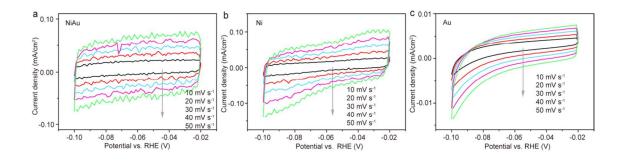


Figure S5. Electrochemical cyclic voltammetry curves of a, NiAu/TiO₂/n-Si, b, Ni/TiO₂/n-Si and c, Au/TiO₂/n-Si photoanodes at different scanning rates.

S4. FDTD solutions method

A UV-VIS (NIR) Spectrophotometer (Lambda950) was used to record optical transmission spectra of the Au nanoparticles. Finite-difference-time-domain (FDTD) was also used to simulate the UV-visible absorbance. The dimensions for FDTD calculation are extracted from the AFM image (Figure 1c).

For simplicity, the Au and Ni nanoparticles were considered as nanospheres, where the diameter was 2 nm. Au nanoparticles (yellow) were distributed on the 2 nm TiO₂ film and 100 nm n-Si wafer, while Ni nanoparticles (green) were embedded on the interspace of the Au

nanoparticles (yellow). To get the precise optical characteristics, the grid was set to 0.05 nm and the simulation time as 1000 fs. The optical constants of Si, Au, Ni, and TiO₂ were taken from Palik. S10 A 546 nm plane wave light with normal incident was used to simulate the spatial distribution of plasmonic field for NiAu/TiO₂/n-Si photoanode (Figure 5a), as shown in figure S6. The simulation area was marked by the red dashed line frame.

The simulation for UV-visible absorbance spectra in Figure 3d was of the same parameters, besides the absence of n-Si substrate and TiO₂ layer. Only NiAu catalyst was modeled to study the absorption since the absorption of n-Si substrate was used to be the base line in the measured absorbance spectra and TiO₂ layer had a negligible impact on absorption with the wavelength larger than 440 nm.

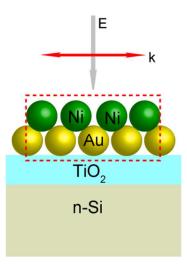


Figure S6. The calculation models of Au and Ni nanoparticles complex arrays employed in the simulation by the finite-difference-time-domain (FDTD) solutions.

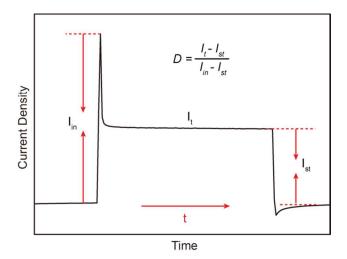


Figure S7. The scheme for the calculation of the transient dynamics is constant, the inset shows the equation of the normalized parameter (D).

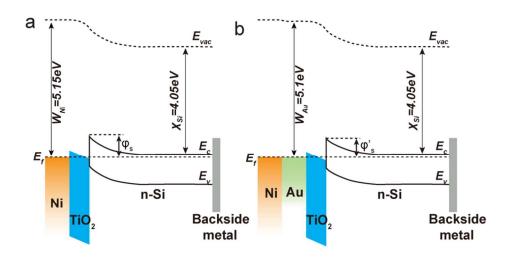


Figure S8. Approximate energy band diagram with respect to the vacuum level of a), Ni/TiO₂/n-Si structure and b), NiAu/TiO₂/n-Si structure.

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